SCAS012B - D2957, JULY 1987 - REVISED APRIL 1993

- Inputs Are TTL-Voltage Compatible
- Flow-Through Architecture Optimizes PCB Layout
- Center-Pin V_{CC} and GND Configurations Minimize High-Speed Switching Noise
- EPIC[™] (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

description

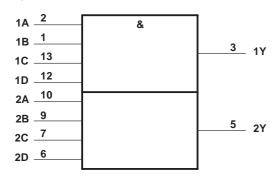
These devices contain two independent 4-input AND gates. They perform the Boolean functions $Y = A \cdot B \cdot C \cdot D$ or $Y = \overline{A} + \overline{B} + \overline{C} + \overline{D}$ in positive logic.

The 54ACT11021 is characterized for operation over the full military temperature range of -55° C to 125°C. The 74ACT11021 is characterized for operation from -40° C to 85°C.

FUNCTION TABLE (each gate)

	INP	OUTPUT		
Α	В	С	D	Y
Н	Н	Н	H	Н
L	Χ	X	X	L
Х	L	X	X	L
Х	Χ	L	Χ	L
X	Χ	X	L	L

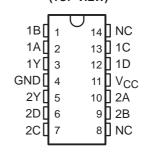
logic symbol†



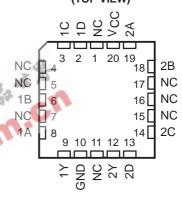
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the D, J, and N packages.

54ACT11021 . . . J PACKAGE 74ACT11021 . . . D OR N PACKAGE (TOP VIEW)

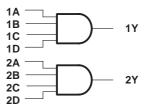


54ACT11021 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, V _O (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Storage temperature range	– 65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		54ACT11021		74ACT	UNIT	
	4	MIN	MAX	MIN	MAX	UNII
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	VCC	0	VCC	V
VO	Output voltage	0	VCC	0	VCC	V
IOH	High-level output current		-24		-24	mA
lOL	Low-level output current		24		24	mA
Δt/Δν	Input transition rise or fall rate	0	10	0	10	ns/V
TA	Operating free-air temperature	-55	125	- 40	85	°C



NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST COMPITIONS	vcc	T _A = 25°C			54AC	Γ11021	74ACT11021		UNIT
PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
	I _{OH} = - 50 μA	4.5 V	4.4			4.4		4.4		$\left\{ \right]$
		5.5 V	5.4			5.4		5.4		
Vari	I _{OH} = – 24 mA	4.5 V	3.94			3.7		3.8		V
VOH	10H = - 24 IIIA	5.5 V	4.94			4.7		4.8		V
	$I_{OH} = -50 \text{ mA}^{\ddagger}$					3.85				
	$I_{OH} = -75 \text{ mA}^{\ddagger}$	5.5 V						3.85		
	ΙΟL = 50 μΑ	4.5 V			0.1		0.1		0.1	
		5.5 V			0.1		0.1		0.1	
V	I _{OL} = 24 mA	4.5 V			0.36		0.5		0.44	V
VOL		5.5 V			0.36		0.5		0.44	
	$I_{OL} = 50 \text{ mA}^{\ddagger}$	5.5 V					1.65			
	I _{OL} = 75 mA [‡]	5.5 V			9				1.65	
lį	V _I = V _{CC} or GND	5.5 V			± 0.1		± 1		± 1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V	- 20	- 34	4		80		40	μΑ
Δl _{CC} §	One input at 3.4 V, Other inputs at GND or V _{CC}	5.5 V	33	3	0.9		1		1	mA
C _i	V _I = V _{CC} or GND	5 ∨		3 .5					·	pF

[‡] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	T _A = 25°C		54ACT11021		74ACT11021		UNIT	
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX MIN MAX	ONIT		
^t PLH	Any	Y	1.5	6.7	8.8	1.5	10.4	1.5	9.8	
^t PHL			1.5	5.4	8.3	1.5	9.5	1.5	8.9	ns

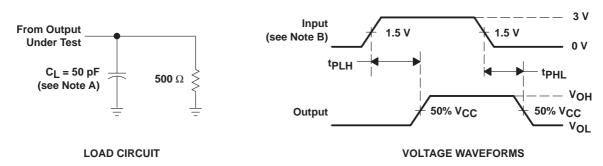
operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS	TYP	UNIT
Cpd	Power dissipation capacitance per gate	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	37	pF

[§] This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.

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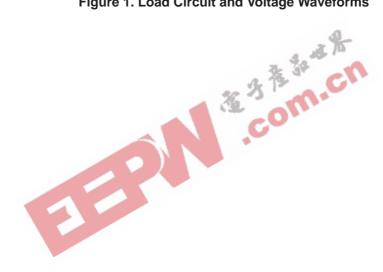
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$, $t_f = 3 \ ns$, $t_f = 3 \ ns$.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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